STEALTH[™] Diode

50 A, 600 V

FFH50US60S

Description

The FFH50US60S is a STEALTH^{imessilon} diode optimized for low loss performance in output rectification. The STEALTH family exhibits low reverse recovery current (I_{RR}), low V_F and soft recovery under typical operating conditions. This device is intended for use as an output rectification diode in Telecom power supplies and other power switching applications. Lower V_F and I_{RR} reduces diode losses.

Features

- Stealth Recovery, $t_{rr} = 113$ ns (@ $I_F = 50$ A)
- Max Forward Voltage, $V_F = 1.54 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Operating Temperature = $175^{\circ}C$
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- SMPS, Welders
- Power Factor Correction
- Uninterruptible Power Supplies
- Motor Drives

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit		
Repetitive Peak Reverse Voltage	V _{RRM}	600	V		
Working Peak Reverse Voltage	V _{RWM}	600	V		
DC Blocking Voltage	V _R	600	V		
Average Rectified Forward Current (T _C = 120°C)	I _{F(AV)}	50	A		
Repetitive Peak Surge Current (20 kHz Square Wave)	I _{FRM}	100	A		
Nonrepetitive Peak Surge Current (Halfwave, 1 Phase, 60 Hz)	I _{FSM}	500	A		
Power Dissipation	PD	200	W		
Avalanche Energy (1 A, 40 mH)	E _{AVL}	20	mJ		
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	–55 to 175	°C		
Maximum Temperature for Soldering Leads at 0.063 in (1.6 mm) from Case for 10 s	ΤL	300	°C		
Maximum Temperature for Soldering Package Body for 10 s	T _{PKG}	260	°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



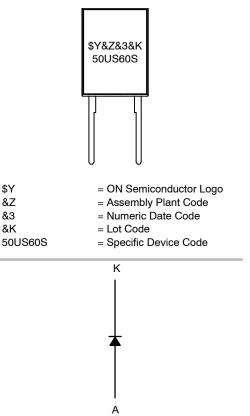
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JEDEC STYLE 2 LEAD CASE 340 CL

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Package	Packing Methode	Reel Size	Tape Width	Quantity
FFH50US60S	FFH50US60S	TO247-2L	Tube	N/A	N/A	30

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test C	onditions	Min.	Тур.	Max.	Unit
FF STATE C	HARACTERISTICS				•		
I _R	Instantaneous Reverse Current	V _R = 600 V	$T_{C} = 25^{\circ}C$	-	-	100	μA
			T _C = 125°C	-	-	1	mA
N CHARACT	ERISTICS						
V _F Instantaneous Forward Voltage	I _F = 50 A	$T_{\rm C} = 25^{\circ}{\rm C}$	-	1.38	1.54	V	
		T _C = 125°C	-	1.37	1.53	V	
YNAMIC CH	ARACTERISTICS						
CJ	Junction Capacitance	V _R = 10 V, I _F = 0 A		-	110	-	pF
WITCHING C	HARACTERISTICS	•					
T _{rr} Reverse Recovery Time	I_F = 1 A, dI _F /dt = 100 A/µs, V _R = 15 V		_	47	80	ns	
	I_F = 50 A, d I_F /dt = 100 A/µs, V _R = 15 V		_	75	124	ns	
T _{rr}	Reverse Recovery Time	I _F = 50 A, dI _F /dt = 200 A/µs, V _R = 390 V, T _C = 25°C		-	113	-	ns
I _{RR}	Reverse Recovery Current			-	9.6	-	Α
Q _{RR}	Reverse Recovered Charge			-	0.9	-	μC
T _{rr}	Reverse Recovery Time	$I_{\rm F}$ = 50 A, dIF/dt = 200 A/µs, V _R = 390 V,		-	235	-	ns
S	Softness Factor (t _b /t _a)	$1_{\rm C} = 125^{\circ}{\rm C}$	T _C = 125°C		1.5	-	-
I _{RR}	Reverse Recovery Current			-	15	-	Α
Q _{RR}	Reverse Recovered Charge			-	2.3	-	μC
T _{rr}	Reverse Recovery Time	I _F = 50 A, dI _F /dt = 1000 A/μs, V _R = 390 V, T _C = 125°C		-	110	-	ns
S	Softness Factor (t _b /t _a)			-	0.8	-	-
I _{RR}	Reverse Recovery Current			-	46	-	Α
Q _{RR}	Reverse Recovered Charge			-	3.1	-	μC
dI _M /dt	Maximum di/dt during t _b			-	1000	-	Α/με
HERMAL CH	ARACTERISTICS						
$R_{\theta JC}$	Thermal Resistance Junction to Case			-	-	0.75	°C/V
					-		

 R_{0JA}
 Thermal Resistance Junction to Ambient
 TO-247
 30
 °C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CURVES

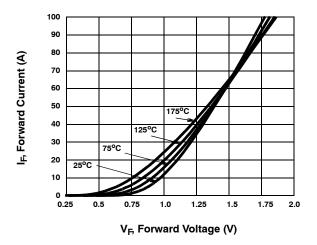


Figure 1. Forward Current vs. Forward Voltage

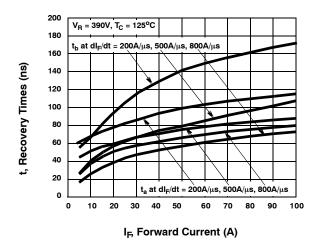
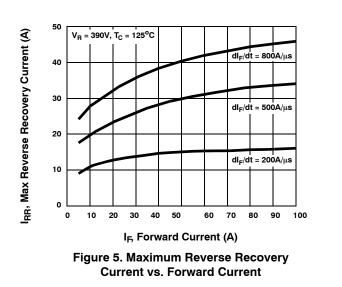


Figure 3. t_a and t_b Curves vs. Forward Current



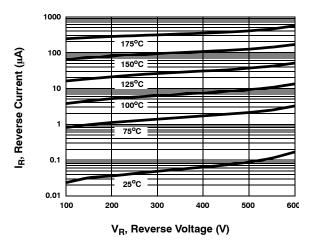
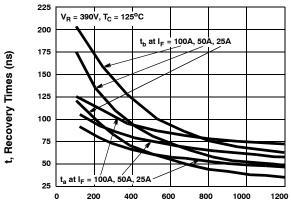
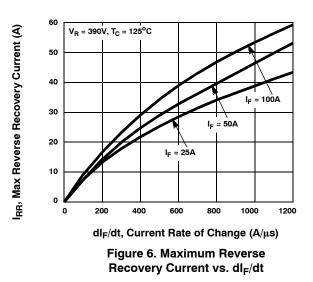


Figure 2. Reverse Current vs. Reverse Voltage



dI_F/dt, Current Rate of Change (A/µs)

Figure 4. t_a and t_b Curves vs. dl_F/dt



TYPICAL PERFORMANCE CURVES

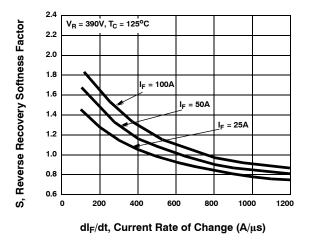


Figure 7. Reverse Recovery Softness Factor vs. dl_F/dt

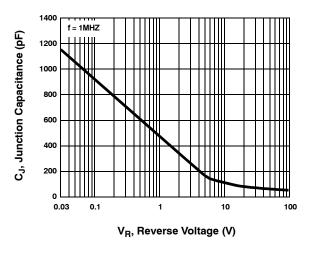


Figure 9. Junction Capacitance vs. Reverse Voltage

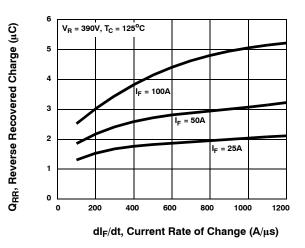


Figure 8. Reverse Recovery Charge vs. dl_F/dt

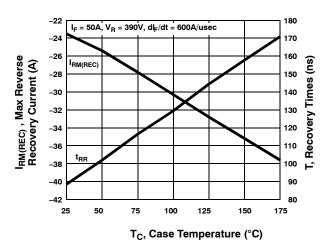


Figure 10. Maximum Reverse Recovery Current and t_{rr} vs. Case Temperature

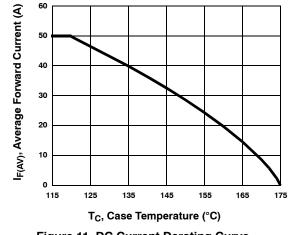


Figure 11. DC Current Derating Curve

TYPICAL PERFORMANCE CURVES

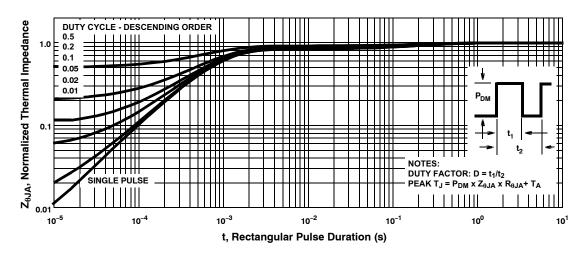


Figure 12. Normalized Maximum Transient Thermal Impedance



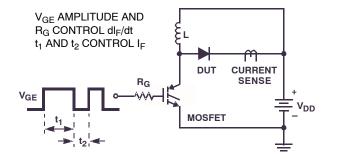


Figure 13. T_{rr} Test Circuit

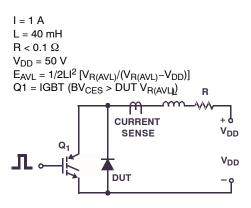


Figure 15. Avalanche Energy Test Circuit

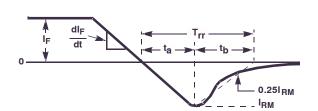


Figure 14. T_{rr} Waveforms and Definitions

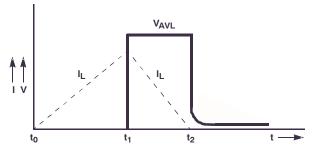


Figure 16. Avalanche Current and Voltage Waveforms

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MILLIMETERS

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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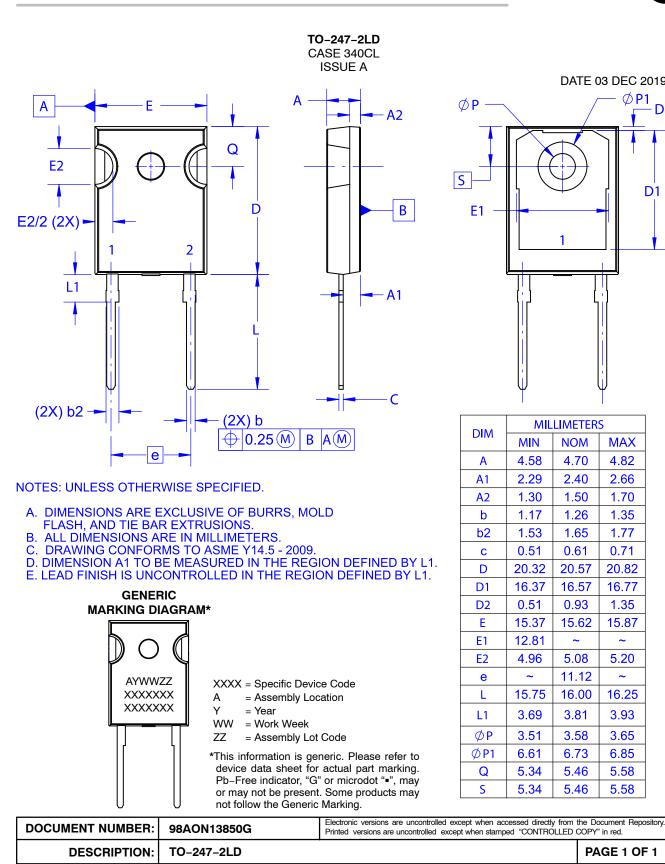
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